



TPS65471 Single-Chip Power and Battery Management IC for Li-Ion Powered Systems

1 Features

- 40-Pin QFN package (6 mm x 6 mm) with PowerPAD™
- Integrated Dynamic Power Path Circuitry (VBUS, VAC, VBAT) With Power Good Signal Outputs and Reverse Current Protection
- 550-mA Li-Ion Battery Charger With 2 State Pins and Safety Timers
- Integrated 4.25-V Synchronous Boost Converter (PWM) and LDO to Provide Voltage Source for LEDs
- 4 LDOs for Each Function in the System
- USB Suspend Mode
- Reset Output
- 3 LED Drivers With PWM Control
- Integrated 3.0-V LDO Regulators
- Integrated 3.2-V LDO Regulators
- A Motor Driver Control
- LDO Regulators and Boost Converter On/Off Control
- Status Outputs to Indicate the Status of the Linear Charger
- Reverse Current Prevention and Thermal Shut Down Circuitry

2 Applications

Handheld Devices

3 Description

TPS65471 integrates a Li-ion linear charger, power path management, four LDO regulators, 4.25-V synchronous boost converter and 4.25-V LDO regulator, three LED drivers and one motor driver.

With the power path circuitry, USB-port, AC-DC adapter and Li-ion battery power can be switched seamlessly as the power source of 3.2-V LDO output regulators. This prevents instability in the system.

The TPS65471 charger automatically selects the USB port or the AC-DC adapter.

The EN_VLDO digital input is used to turn the output of VLED4P25, VLD02 and VLD04 on or off.

The EN_VLDO3 digital input is used to turn the output of VLDO3 on or off.

The TPS65471 is available in a 40-pin QFN package with PowerPAD™.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPS65471	VQFN (40)	6.00 mm x 6.00 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Charging Profile

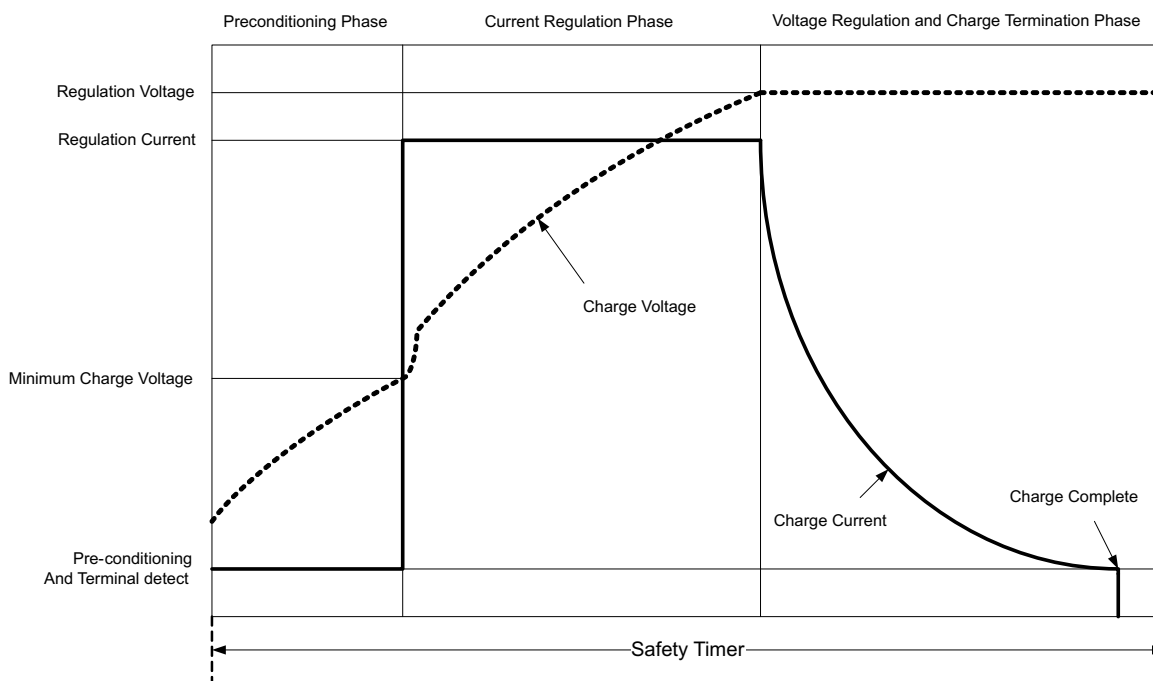


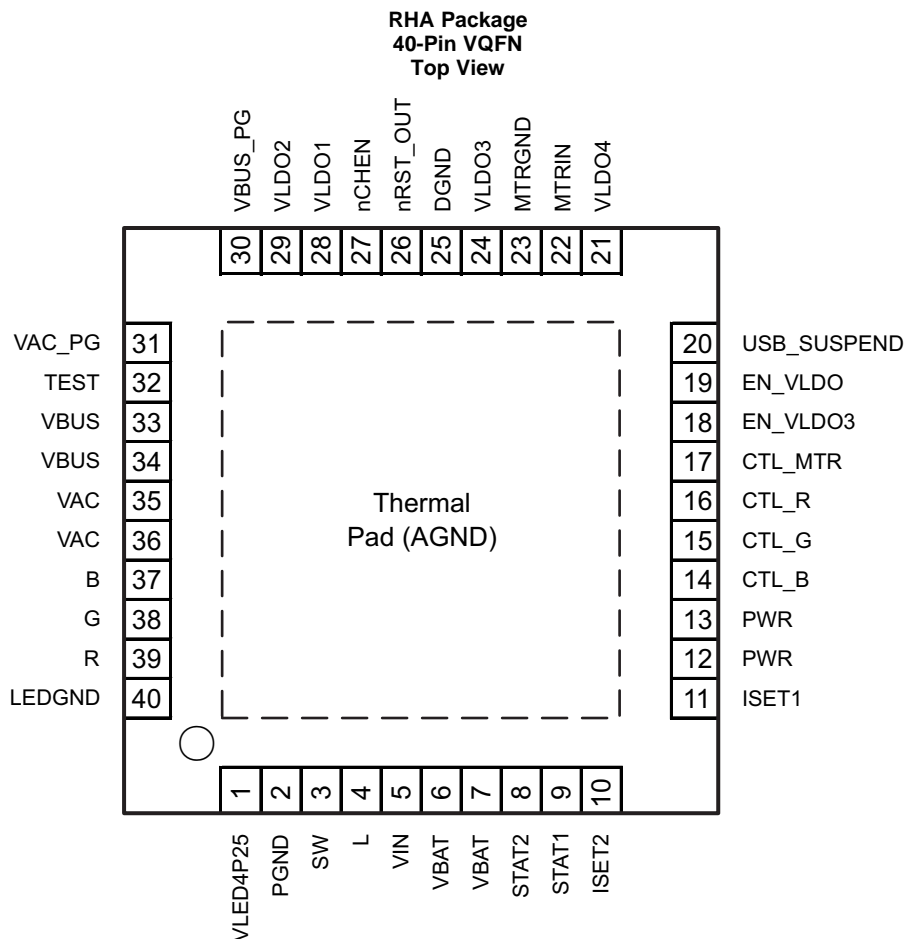
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4 Revision History

Changes from Original (June 2012) to Revision A	Page
<ul style="list-style-type: none"> Added <i>Pin Configuration and Functions</i> section, <i>Feature Description</i> section, <i>Application and Implementation</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section 	1

5 Pin Configuration and Functions



Pin Functions

PIN		DESCRIPTION	EXTERNAL REQUIRED COMPONENTS (SEE TYPICAL APPLICATION)
NAME	NO.		
VAC	35, 36	Power input from AC-DC adapter	1-μF capacitor to AGND to minimize overvoltage transients during AC power hot-plug events. Also Zener diode for surge protection is connected.
VBUS	33, 34	Power input from USB-port	1-μF capacitor to AGND to minimize overvoltage transients during BUS power hot-plug events. Also Zener diode for surge protection is connected.
VBUS_PG	30	VBUS power-good status output. (CMOS output)	Can be used to indicate Power Good signal to system.
VAC_PG	31	VAC power-good status output (CMOS output)	Can be used to indicate Power Good signal to system.
STAT1	9	Charge status output 1 (open-drain output)	Connect 100-kΩ external pullup resistor between STAT1 and VLDO1.
STAT2	8	Charge status output 2 (open-drain output)	Connect 100-kΩ external pullup resistor between STAT2 and VLDO1.
ISET1	11	Charge current set point for VBUS input	External resistor from ISET1 pin and AGND pin sets charge current value when the power input from USB-port.
ISET2	10	Charge current set point for VAC input	External resistor from ISET1 pin and ISET2 pin sets charge current value when the power input from AC-DC adapter.
nCHEN	27	Charge enable input (active low)	Charge enable signal from system.
VIN	5	Power input for boost regulator. It is connected to the Li-ion battery.	Connect to Li-ion battery positive terminal. Connect 22-μF capacitor from VIN pin to PGND.

Pin Functions (continued)

PIN		DESCRIPTION	EXTERNAL REQUIRED COMPONENTS (SEE TYPICAL APPLICATION)
NAME	NO.		
L	4	The inductor is connected between this pin and the SW pin	6.8-μH inductor to SW pin.
SW	3	Switching node of the IC. Connect the inductor between this pin and the L pin.	6.8-μH inductor to L pin.
VLED4P25	1	LDO and synchronous boost converter output	22-μF capacitor to PGND. Connect series resistor for current limitation to each LED (R,G,B).
PGND	2	Synchronous boost converter power ground	Connect to ground plane.
VBAT	6, 7	Power input and output for Li-ion battery	Connect to Li-ion battery positive terminal. Connect 1-μF capacitor from VBAT pin to AGND.
R	39	Output for Red LED driver. The open-drain output pulls low when the CTL_R pin goes to H level. $R_{ON} = 1\ \Omega$ (typical)	Connect to RED input of Red LED.
G	38	Output for Green LED driver. The open-drain output pulls low when the CTL_G pin goes to H level. $R_{ON} = 1\ \Omega$ (typical)	Connect to GREEN input of Green LED.
B	37	Output for Blue LED driver. The open-drain output pulls low when the CTL_B pin goes to H level. $R_{ON} = 1\ \Omega$ (typical)	Connect to BLUE input of Blue LED.
LEDGND	40	LED drivers power ground	Connect to ground plane.
VLDO1	28	LDO output, fixed 3.2 V. The output current of VLDO1 is limited to 20 mA (maximum), when both EN_VLDO and EN_VLDO3 input pins are low level.	1-μF capacitor to AGND
VLDO2	29	LDO output, fixed 3.2 V	1-μF capacitor to AGND
VLDO3	24	LDO output, fixed 3.2 V	1-μF capacitor to AGND
VLDO4	21	LDO output, fixed 3.0 V	1-μF capacitor to AGND
nRST_OUT	26	System reset output, generated according to the VLDO1 output voltage (open-drain output). Connect 100-kΩ internal pullup resistor between nRST_OUT and VLDO1.	Can be used to indicate the reset output signal to system.
MTRIN	22	Motor driver output. The open-drain output pulls low when the CTL_MTR pin goes to H level. $R_{ON} = 1\ \Omega$ (typical)	Can be used to drive motor.
CTL_MTR	17	Control input for motor driver (active H)	Motor driver control input signal from system
MTRGND	23	Motor driver power ground	Connect ground plane
CTL_B	14	Control input for (B pin) Blue LED driver (active H)	Blue LED driver control input signal from system
CTL_G	15	Control input for (G pin) Green LED driver (active H)	Green LED driver control input signal from system
CTL_R	16	Control input for (R pin) Red LED driver (active H)	Red LED driver control input signal from system
DGND	25	Digital ground	Connect to ground plane.
PWR	12,13	Power path output. The power supply for each LDO.	10-μF capacitor to AGND. Regarding an effect of DC bias on capacitor, select a capacitor that can secure at least 4.7-μF in worse case.
EN_VLDO	19	Enable input for VLDO2, VLDO4 and VLED4P25 (active H)	LDO2, LDO4 and 4.25 VLDO control input signal from system
EN_VLDO3	18	Enable input for VLDO3	LDO3 control input signal from system
TEST	32	Test pin. Normally open.	
USB_SUSPEND	20	Control input for USB suspended mode. To reduce supply current from VBUS (active H).	USB suspended input signal from system
Thermal Pad (AGND)		Analog ground (AGND) input. Thermal ground should be soldered to the analog ground, use thermal via to connect to ground plane for ideal power dissipation.	Connect the PowerPAD to ground plane.

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Input voltage	VBUS, VAC, PWR, SW, ISET1, ISET2	−0.3	7	V
	VBAT, VLDO1, VLDO2, VDLO3, VDLO4, VLED4P25, VIN, L, R, G, B, MTRIN	−0.3	5.5	
	nCHEN, USB_SUSPEND, CTL_R, CTL_G, CTL_B, CTL_MTR, EN_VLDO, EN_VLDO3, nRST_OUT, VBUS_PG, VAC_PG, STAT1, STAT2	−0.3	3.6	
Output sink/source current	VBUS_PG, VAC_PG, nRST_OUT, STAT1, STAT2		15	mA
Operating junction temperature		−40	150	°C
Storage temperature range, T _{stg}		−65	150	°C

- (1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under [Recommended Operating Conditions](#) is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾⁽²⁾⁽³⁾

		MIN	MAX	UNIT
V _{VBUS}	Supply voltage (VBUS)	4.75	5.25	V
V _{VAC}	Supply voltage (VAC)	4.75	5.75	V
V _{VBAT1}	Supply voltage (VBAT) for linear charger	2.7	4.3	V
V _{VBAT2}	Supply voltage (VBAT) for 4.25-V boost output	3.2	4.3	V
T _A	Operating ambient temperature	−10	85	°C
T _J	Operating junction temperature	−10	125	°C

- (1) Current dissipation and junction temperature must be confirmed on maximum V_{VBUS}, V_{VAC} and V_{VBAT}.
(2) If any V_{VBUS} or V_{VAC} or V_{VBAT} is a recommended operating condition, this device can operate. Refer to [Table 1](#).
(3) LDO1 operates when the output voltage of LDO1 is less than V_{RST}.

6.3 Thermal Information

THERMAL METRIC ⁽¹⁾		TPS65471	UNIT
		RHA (VQFN)	
		40 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	30.1	°C/W

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

6.4 Electrical Characteristics

over −10°C < T_J < 125°C and recommended supply voltage (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
INPUT CURRENT					
I _{VAC}	Active supply current from VAC No load, EN_VLDO = H, EN_VLDO3 = H, nCHEN = H, USB_SUSPEND = L, VBAT = 3.8 V, VAC = 5.25 V		237		μA
I _{VBUS}	Active supply current from VBUS No load, EN_VLDO = H, EN_VLDO3 = H, nCHEN = H, USB_SUSPEND = L, VBAT = 3.8 V, VAC = 5 V		237		μA
I _{VBUS(USPND)}	VBUS current at USB suspend mode No load, EN_VLDO = H, EN_VLDO3 = H, nCHEN = H, USB_SUSPEND = H, VBAT = 2.8 V, VAC = 5.25 V		207	290	μA
I _{VBAT}	Active supply current from VBAT No load, EN_VLDO = H, EN_VLDO3 = H, nCHEN = H, USB_SUSPEND = L, VBAT = 4.2 V		1.4		mA

Electrical Characteristics (continued)

over $-10^{\circ}\text{C} < T_J < 125^{\circ}\text{C}$ and recommended supply voltage (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I _{VBAT(STBY)}	VBAT standby current	No load, EN_VLDO = L, EN_VLDO3 = L, nCHEN = H, USB_SUSPEND = L, VBAT = 4.2 V, T _J = 60°C		56	88	μA
I _{VBAT(SUP)}	Sleep current at VBAT	Sum of current into VBAT pin. VBAT = 2.5 V < V _(BATUVLO) At nCHEN=H and state #01, 02, 03, 04, 09, 10, T _J = 60°C		3		μA
UVLO/PG COMPARATOR/OVER DISCHARGE PROTECTION FOR LI-ION						
V _(VBUSPG)	Power good threshold voltage for VBUS	At VBUS pin, L to H	4.08	4.25	4.42	V
V _(VBUSPGHYS)	Hysteresis voltage on V _(VBUSPG)	At VBUS pin, V _(VBUSPG) - V _(VBUSPGHYS) is threshold voltage for H to L		100		mV
V _(VACPG)	Power good threshold voltage for VAC	At VAC pin, L to H	4.08	4.25	4.42	V
V _(VACPGHYS)	Hysteresis voltage on V _(VACPG)	At VAC pin, V _(VAC) - V _(VACHYS) is threshold voltage for H to L		100		mV
V _(BATUVLO)	Under voltage lock out voltage for Li-ion	At VBAT pin	2.6	2.7	2.8	V
V _{BATmin(BATUVLO)}	Minimum V _{BAT} for over discharge protection	At VBAT pin ⁽¹⁾		1.5		V
t _{dly(BATUVLO)}	Li-ion UVLO deglitch time	Only for falling edge (H to L)		420		μs
POWER PATH						
R _{ON(BUS)}	Resistance of a FET between VBUS and PWR	VBUS = 4.75 V		130		mΩ
R _{ON(AC)}	Resistance of a FET between VAC and PWR	VAC = 4.75 V		130		mΩ
R _{ON(BAT)}	Resistance of a FET between VBAT and PWR	VABT = 3.3 V		50		mΩ
		VBAT = 3.3 V, EN_VLDO = L, EN_VLDO3 = L		5		Ω
LDO REGULATORS						
LDO4 (C _{OUT} = 1 μF, 3.4 V < PWR < 5.75 V)						
V _(VLDO4)	VLDO4 output voltage	3.4 V < PWR < 5.75 V	2.9	3	3.1	V
I _(VLDO4)	VLDO4 output current		1		150	mA
V _{DO(VLDO4)}	VLDO4 dropout voltage	I _O = 150 mA		0.14		V
I _(VLDO4_ILMT)	VLDO4 output current limit		350			mA
PSRR _(VLDO4)	Power supply rejection ratio			-60		dB
LDO1 (C _{OUT} = 1 μF, 3.4 V < PWR < 5.75 V)						
V _(VLDO1)	VLDO1 output voltage	3.4 V < PWR < 5.75 V	3.136	3.2	3.264	V
I _(VLDO1)	VLDO1 output current		1		100	mA
V _{DO(VLDO1)}	VLDO1 dropout voltage	I _O = 100 mA		0.12		V
I _(VLDO1_ILMT)	VLDO1 output current limit			250		mA
PSRR _(VLDO1)	Power supply rejection ratio			-60		dB
R _{ON(VLDO1_dichg)}	Discharge resistance on VLDO1			630		Ω
RESET CIRCUIT						
V _(RST)	Reset threshold voltage	At VLDO1, H to L	2.7	2.8	2.9	V
V _(RSTHYS)	Hysteresis voltage for reset	At VLDO1, V _(RST) + V _(RSTHYS) is threshold voltage for L to H		140		mV
LDO2 (C _{OUT} = 1 μF, 3.4 V < PWR < 5.75 V)						
V _(VLDO2)	VLDO2 output voltage	3.4 V < PWR < 5.75 V	3.136	3.2	3.232	V
I _(VLDO2)	VLDO2 output current		1		30	mA
V _{DO(VLDO2)}	VLDO2 dropout voltage	I _O = 30 mA		0.03		V
I _(VLDO2_ILMT)	VLDO2 output current limit			250		mA
PSRR _(VLDO2)	Power supply rejection ratio			-60		dB

(1) Not tested in production.

Electrical Characteristics (continued)

over $-10^{\circ}\text{C} < T_J < 125^{\circ}\text{C}$ and recommended supply voltage (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
LDO3 (C _{OUT} = 1 μF, 3.4 V < PWR < 5.75 V)						
V _(VLDO3)	VLDO3 output voltage	3.4 V < PWR < 5.75 V	3.136	3.2	3.264	V
I _(VLDO3)	VLDO3 output current		1		150	mA
V _{DO(VLDO3)}	VLDO3 dropout voltage	I _O = 150 mA		0.13		V
I _(VLDO3_ILMT)	VLDO3 output current limit			250		mA
PSRR _(VLDO3)	Power supply rejection ratio			−60		dB
LINEAR CHARGER						
VOLTAGE REGULATION (V _{O(REG)} + V _(DO_MAX) < V _{PWR} , I _(TERM) < I _{O(OUT)} < 550 mA)						
V _{O(REG)}	Output voltage			4.2		V
A _{CC(REG)}	Voltage regulation accuracy	T _A = 25°C, I _{O(OUT)} = 50 mA	−0.35		0.35	%
		See ⁽²⁾	−1		1	
V _(DO)	Dropout voltage (V _(PWR) - V _(OUT))			350	500	mV
CURRENT REGULATION						
I _{O(OUT)}	Output current range	V _{PWR} > V _(LOWV) V _{PWR} - V _{VBAT} > V _(DO) V _{PWR} > 4.6 V	50		550	mA
V _(SET)	Output current set voltage	Voltage on ISET1 pin, V _{PWR} = 4.85 V, I _{O(OUT)} = 550 mA V _{BAT} = 4 V	2.463	2.5	2.538	V
K _(SET)	Output current set factor	V _{PWR} = 4.85 V, I _{O(OUT)} = 60 mA V _{BAT} = 2.8 V, Pre-charge mode	299	319	339	
		V _{PWR} = 4.85 V, I _{O(OUT)} = 60 mA V _{BAT} = 4 V, CC mode	285	321	357	
		V _{PWR} = 4.85 V, I _{O(OUT)} = 550 mA V _{BAT} = 4 V, CC mode	307	322	337	
PRECHARGE AND SHORT-CIRCUIT CURRENT REGULATION						
V _(LOWV)	Precharge to fast-charge transition threshold	Voltage on VBAT pin	2.8	3	3.2	V
t _(DEG-FLOP)	Deglitch time for fast-charge to precharge transition	V _{PWR(min)} > 4.6 V, t _{FALL} = 100 ns, 10-mV overdrive, VBAT decreasing below threshold.	250	375	500	ms
I _{O(PRECHARGE)}	Precharge range	0 V < V _{PWR} < V _(LOWV) , t < t _(PRECHG)	5		55	mA
V _(PRECHG)	Precharge set voltage	Voltage on ISET1 pin, V _{O(REG)} = 4.2 V, 0 V < V _{PWR} > V _(LOWV) , t < t _(PRECHG)	235	250	265	mV
TERMINATION DETECTION						
I _(TERM)	Charge termination detection range	V _{BAT} > V _(RCH) , t < t _(TRMDET)	5		55	mA
V _(TERM)	Charge termination detection set voltage	Voltage on ISET1 pin, V _{O(REG)} = 4.2 V V _{BAT} > V _(RCH) , t < t _(TRMDET)	235	250	265	mV
t _(TRMDET)	Deglitch time for termination detection	V _{PWR(min)} > 4.6 V, t _{FALL} = 100 ns, Charging current decreasing below 10-mV overdrive	250	375	500	ms

(2) Specified by characterization. Not tested in production.

Electrical Characteristics (continued)

over $-10^{\circ}\text{C} < T_J < 125^{\circ}\text{C}$ and recommended supply voltage (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
BATTERY RECHARGE THRESHOLD						
V _(RCH)	Recharge threshold	T _A = 25°C	V _{O(REG)} - 0.115	V _{O(REG)} - 0.10	V _{O(REG)} - 0.085	V
t _(DEGL)	Deglitch time for recharge detect	V _{PWR(min)} > 4.6 V, t _{FALL} = 100 ns, Decreasing below or increasing above threshold, 10-mV overdrive	250	375	500	ms
TIMERS						
t _(PRECHG)	Precharge time		1620	1800	1989	s
t _(CHG)	Charge time		22680	25200	27720	s
I _(FAULT)	Timer fault recovery current			200		μA
t _(TMRRST)	Deglitch time to reset timers when disabling charger		250	375	500	ms
BATTERY CHARGER ON/OFF COMPARATOR						
V _(CHGOFF)	Charger off threshold voltage	2.7 V < V _{BAT} < V _{O(REG)}	V _{PWR} < V _{BAT} + 80 mV			V
V _(CHGON)	Charger on threshold voltage	2.7 V < V _{BAT} < V _{O(REG)}	V _{PWR} > V _{BAT} + 110 mV			V
ISET2						
R _{ON(ISET2)}	N-channel MOSFET on-resistance between ISET2 and GND	V _{AC} = 4.75 V	4			Ω
4.25-V BOOST AND LDO (C _{OUT} = 22 μF, L = 6.8 μH, C _{IN} = 22 μF)						
V _(VLED4P25)	VLED4P25 output voltage	3.2 V < V _{BAT} < 4.3 V for boost or 4.6 V < PWR < 5.75 V for LDO	4.165	4.25	4.335	V
I _(VLED4P25)	VLED4P25 output current		1		140	mA
4.25-V LDO						
I _(VLED4P25_ILMT)	4.25-V LDO output current limit	4.6 V < PWR < 5.75 V		250		mA
V _{DO(VLED4P25)}	4.25-V LDO dropout voltage	I _O = 140 mA			0.35	V
PSRR _(VLED4P25)	Power supply rejection ratio			-60		dB
4.25-V BOOST						
f _{OSC_VLED4P25}	4.25-V boost switching frequency			555		kHz
I _(VLED4P25_Boost_ILMT)	4.25-V boost output current limit	3.2 V < V _{BAT} < 4.3 V		800		mA
R _{ON(ISO)}	Isolation MOSFET on-resistance between VIN and L	V _{BAT} = 3.2 V		300		mΩ
R, G, B OUTPUTS						
R _{ON(R)}	N-channel MOSFET on-resistance between R and LEDGND			1		Ω
R _{ON(G)}	N-channel MOSFET on-resistance between G and LEDGND			1		Ω
R _{ON(B)}	N-channel MOSFET on-resistance between B and LEDGND			1		Ω
MTRIN OUTPUT						
R _{ON(MTR)}	N-channel MOSFET on-resistance between MTRIN and MTRGND			1		Ω
CTR_R, CTL_G, CTL_B, CTL_MTR, EN_VLDO, EN_VLDO3, USB_SUSPEND AND nCHEN INPUTS						
V _{IL}	Low level input voltage	VLDO1 = 3.2 V	0.3 x VLDO1			V
V _{IH}	High level input voltage	VLDO1 = 3.2 V	0.7 x VLDO1			V
R _{PD(CTL_R)}	Pull-down resistor (CTL_R)			1000		kΩ
R _{PD(CTL_G)}	Pull-down resistor (CTL_G)			1000		kΩ
R _{PD(CTL_B)}	Pull-down resistor (CTL_B)			1000		kΩ
R _{PD(CTL_MTR)}	Pull-down resistor (CTL_MTR)			100		kΩ
R _{PD(EN_VLDO)}	Pull-down resistor (EN_VLDO)			100		kΩ
R _{PD(EN_VLDO3)}	Pull-down resistor (EN_VLDO3)			100		kΩ
R _{PD(USB_SUSPEND)}	Pull-down resistor (USB_SUSPEND)			100		kΩ
R _{PU(nCHEN)}	Pull-up resistor (nCHEN) to VLDO1			100		kΩ

Electrical Characteristics (continued)

over $-10^{\circ}\text{C} < T_J < 125^{\circ}\text{C}$ and recommended supply voltage (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
VBUS_PG, VAC_PG OUTPUTS						
V _{OH(PG)}	High-level output saturation voltage	3.4 V < PWR < 5.75 V, I _O = -500 μA, VDD = VLDO1	VDD - 0.25			V
V _{OL(PG)}	Low-level output saturation voltage	3.4 V < PWR < 5.75 V, I _O = 500 μA, VDD = VLDO1	0.25			V
STAT1, STAT2 OUTPUTS						
V _{OL(STAT)}	Low-level output saturation voltage	I _O = 2.5 mA	0.25			V
nRST_OUT OUTPUT						
V _{OL(nRST)}	Low-level output saturation voltage	I _O = 2.5 mA	0.25			V
R _{PU(nRST)}	Pull-up resistor (nRST_OUT) to VLDO1		100			kΩ
t _{dly(nRST)}	Deglitch time on nRST_OUT		95	125	160	ms
THERMAL SHUTDOWN THRESHOLD						
T _(SHTDWN)	Thermal trip threshold	T _J increasing	150			°C
hys _(SHTDWN)	Thermal hysteresis	T _J increasing	15			°C

6.5 Dissipation Ratings⁽¹⁾

PACKAGE	$T_A < 40^{\circ}\text{C}$ POWER RATING (W)	DERATING FACTOR ABOVE $T_A = 40^{\circ}\text{C}$ (mW/ $^{\circ}\text{C}$)
RHA	2.82	33.2

(1) This data is based on using the JEDEC High-K board and exposed die pad is connected to a Cu pad on the board.

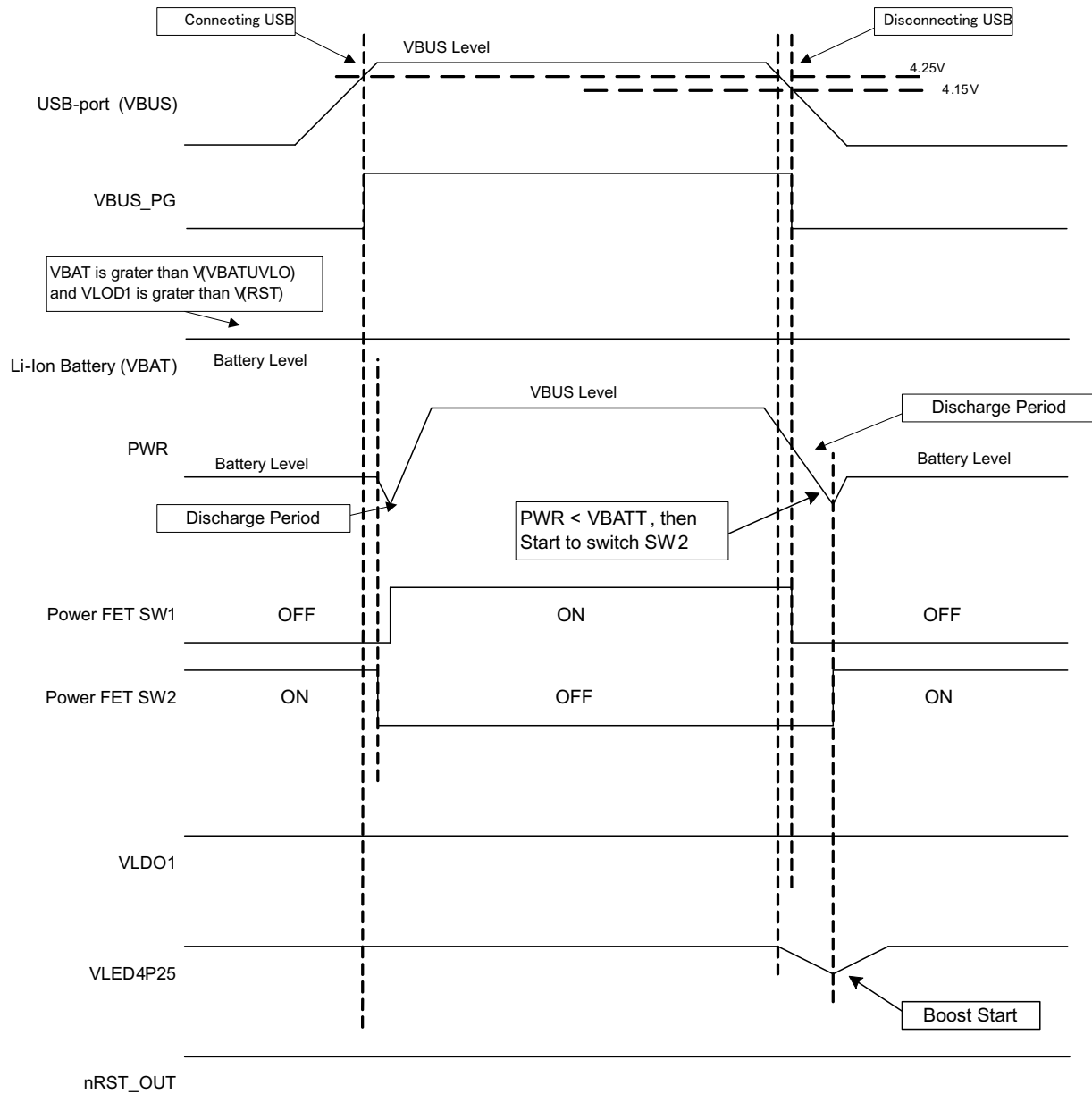


Figure 1. USB-Port Hot-Plug During Battery Operation (#5# → #7# → #5#, Charge Off, EN_VLDO = H)

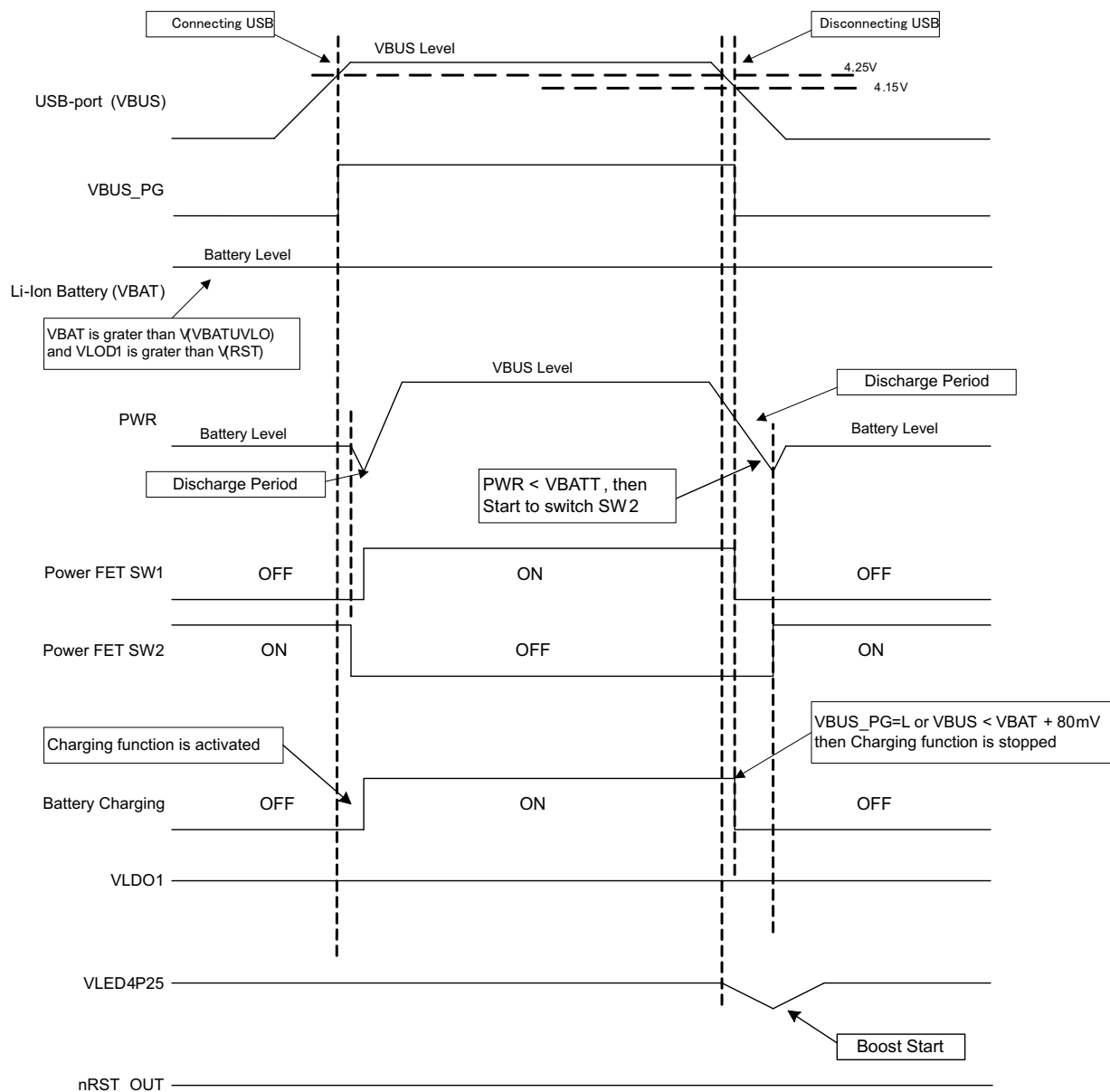


Figure 2. USB-Port Hot-Plug During Battery Operation (#5# → #7# → #5#, Charge On, EN_VLDO = H)

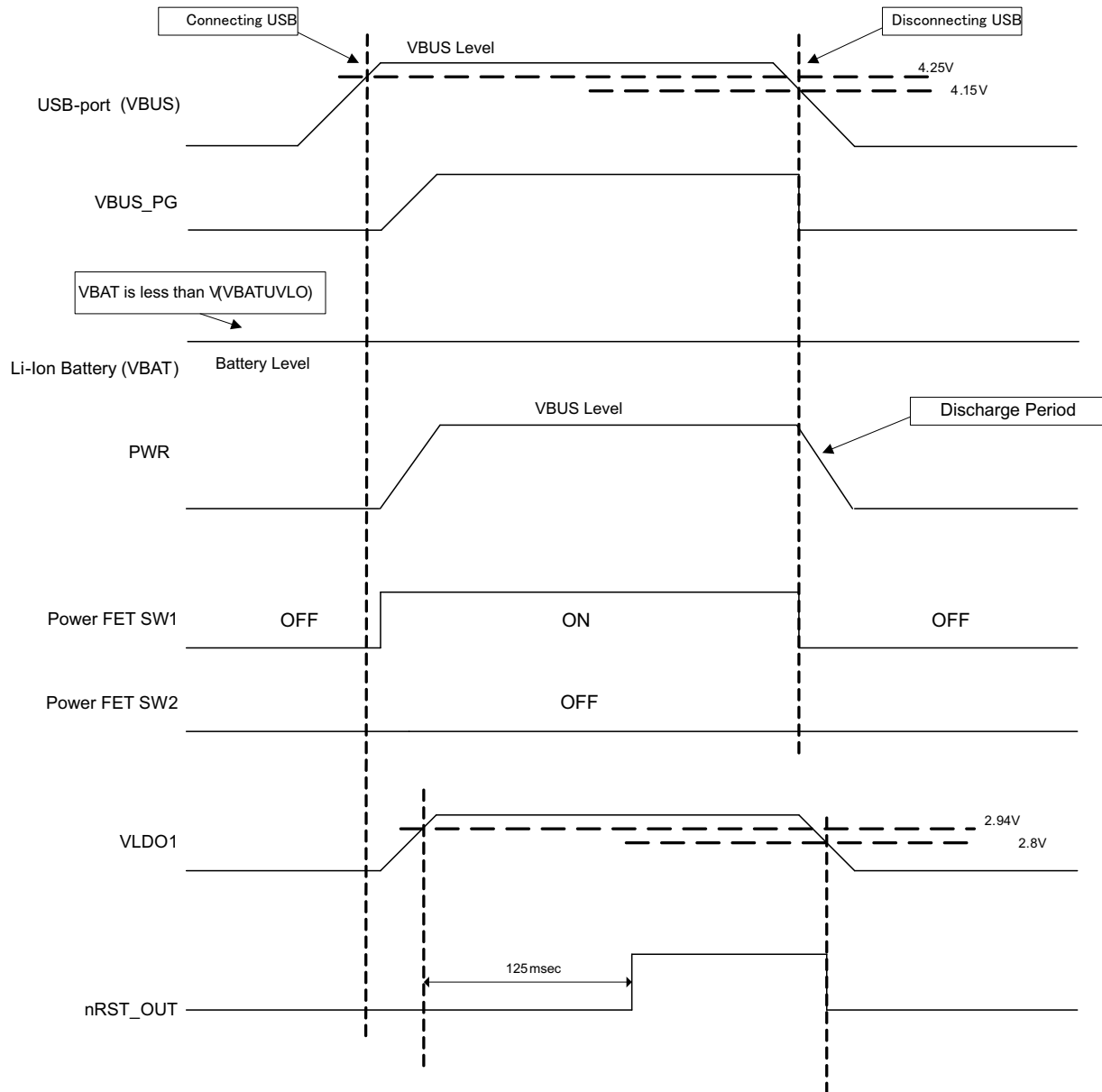


Figure 3. USB-Port Hot-Plug (Absent Battery and VAC, #1# → #3# → #1#)

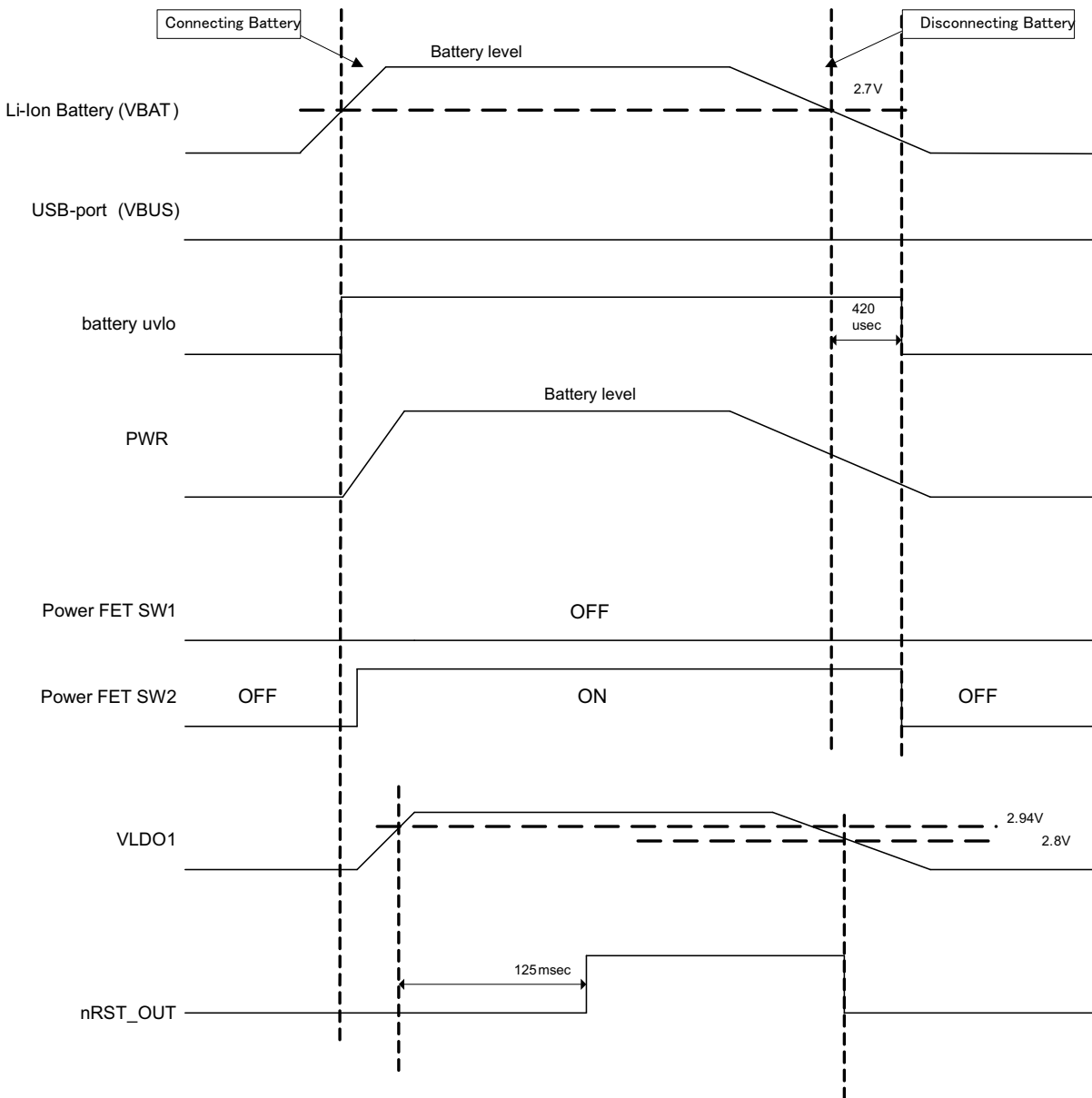


Figure 4. Battery Hot-Plug (Absent VBUS and VAC, #1# → #5# → #1#)

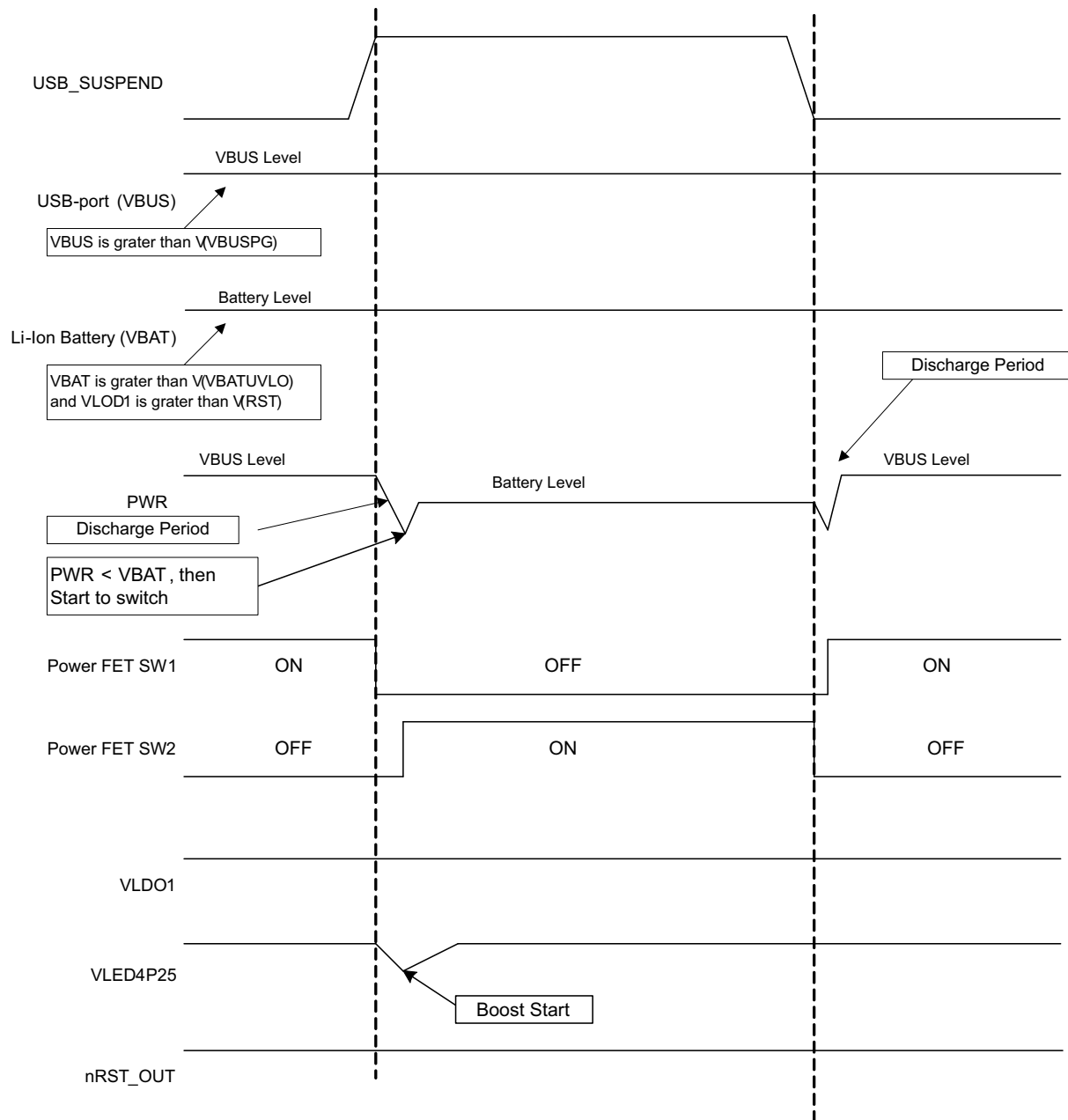
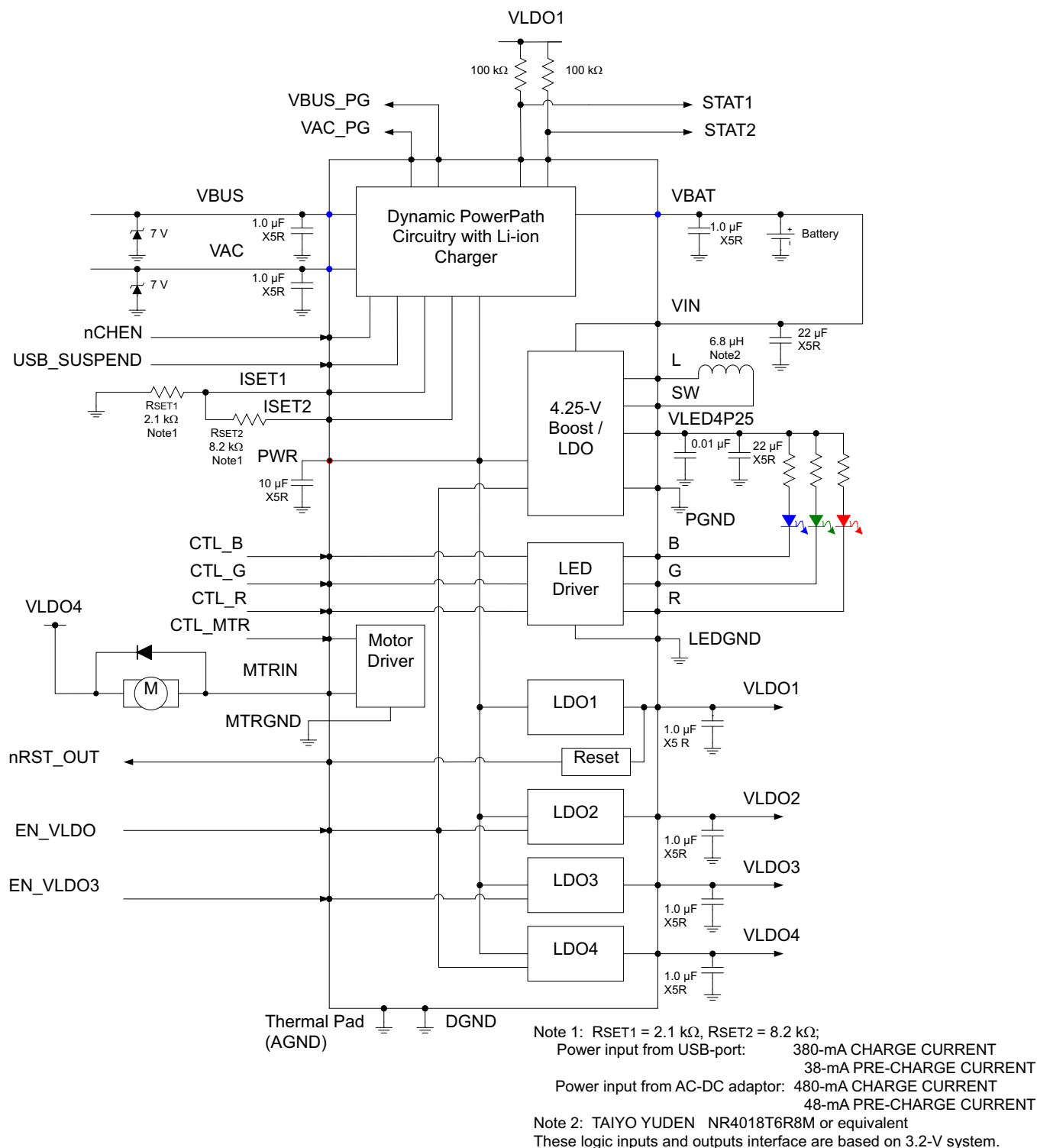


Figure 5. USB Suspend Mode (#7# → #6# → #7#, EN_VLDO = H)

7 Detailed Description

7.1 Functional Block Diagram



7.2 Feature Description

7.2.1 Power Path Function

TPS65471 has a power-path circuitry to choose automatically any one of USB-port (VBUS), AC-DC adapter (VAC) and Li-ion battery (VBAT) as power source for LDOs.

The priority of power selection is VBUS, VAC, then VBAT. When both VBUS and VAC are available, VBUS is used as the power source of the charger and LDOs.

The exception is USB suspend mode, in this cases, power source of charger and LDOs are provided to PWR from VAC.

The VBAT (Li-ion battery) is chosen as a power source when both VBUS (USB-port) and VAC (AC-DC adapter) are not available. In this case, the linear charger function does not operate.

Figure 6 shows an equivalent circuit of the power path. Power FETs SW1, SW2 and SW3 are turned on/off per Table 1 and provide appropriate power sources to each power output.

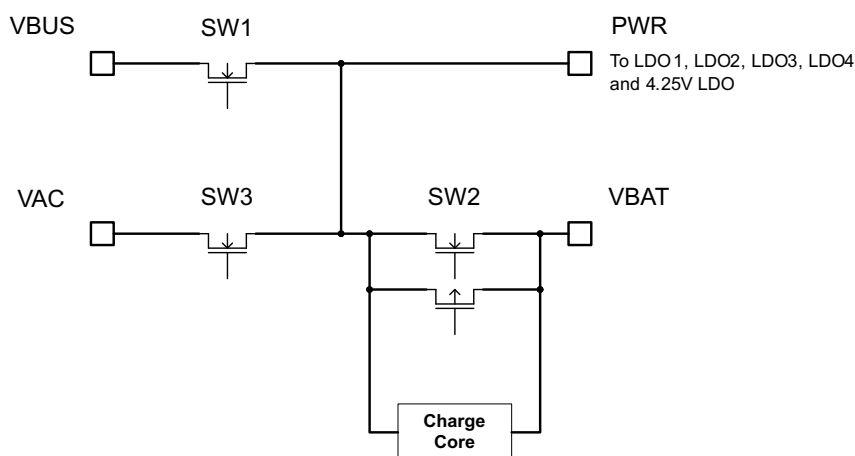


Figure 6. Power Path Circuitry

As Table 1 shows, the state of the linear charger circuitry depends on the state of the power path circuitry. If the power path circuitry is not ready for charging, regardless of nCHEN = L, the charger function is not turned on.

Table 1. Power Path Circuitry Truth Table

AC-DC ADAPTER (VAC)	USB-PORT (VBUS)	LI-ION BATTERY (VBAT)	USB_SUSPEND	POWER SOURCE	STATE	CHARGE STATUS ⁽¹⁾
Absent	Absent	Absent	X	Non	#01#	
Absent	Present	Absent	H	Non	#02# ⁽²⁾	
Absent	Present	Absent	L	VBUS	#03#	nCHEN = L: Recovery - Charge
Present	Absent	Absent	X	VAC	#04#	nCHEN = L: Recovery - Charge
Absent	Absent	Present	X	VBAT	#05#	
Absent	Present	Present	H	VBAT	#06#	
Absent	Present	Present	L	VBUS	#07#	nCHEN = L: Charge
Present	Absent	Present	X	VAC	#08#	nCHEN = L: Charge
Present	Present	Absent	H	VAC	#09#	nCHEN = L: Recovery - Charge
Present	Present	Absent	L	VBUS	#10#	nCHEN = L: Recovery - Charge
Present	Present	Present	H	VAC	#11#	nCHEN = L: Charge
Present	Present	Present	L	VBUS	#12#	nCHEN = L: Charge

(1) For recovery charge, the voltage of VBAT shows the charge state below $V_{(BATUVLO)}$.

(2) At state #2#, while USB_SUSPEND = H, the 3.2-V LDO (VLDO1) is toggled. The USB_SUSPEND signal is detected after the activation of 3.2-V LDO and turns SW1 off. If the 3.2-V LDO is turned off and TPS65471 cannot detect USB_SUSPEND = H, SW1 will turn on and 3.2-V LDO is then deactivated.

7.2.2 USB Suspend Function

TPS65471 has USB suspend function. USB_SUSPEND = H sends TPS65471 into USB suspend mode. While in USB suspend mode, current from the USB host to the VBUS pin is reduced under the USB suspended current.

USB suspend mode does not depend on Li-ion battery status. Even if the Li-ion battery on the VBAT pin is removed or NG. VBUS, which is in USB suspend mode, does not provide electrical power for 3.2-V, 3-V and 4.25-V outputs and these outputs should be disabled.

Even in USB suspend mode, when VAC exists, source power is provided to the 3.2-V, 3-V and 4.25-V outputs from VAC.

This function complies with [Table 1](#).

7.2.3 Standby Function

TPS65471 enters standby mode when the power source Li-ion battery (states #05# and #06#) and both logic inputs of EN_VLDO and EN_VLDO3 are at L level. While in standby mode, current from the Li-ion battery to the VBAT pin is reduced under $V_{VBAT(STBY)}$. The low resistance PMOS FET and NMOS FET are connected to SW2 between the PWR pin and VBAT pin in parallel. In order for the TPS65471 to decrease the power supply current, the PMOS FET operates in standby mode. In standby mode, the PMOS FET turns on corresponding to the output current of the VLDO1 voltage drop of PWR.

To recover from standby mode, the logic input of EN_VLDO or EN_VLDO3 is set to H level, then the low resistance NMOS FET connected between PWR and VBAT turns on. The startup time of the LDOs controlled by these logic input signals is approximately 1 ms.

7.2.4 LDO1

The TPS65471 has a 3.2-V regulator as the LDO1 power and it provides a stable and accurate voltage of 3.2 V (± 64 mV). Complying with [Table 1](#), LDO1 keeps its operation during PWR on. This LDO provides the power supply to the circuit of logic I/O. If PWR power decreases, discharge resistors at VLDO1 will be turned on and discharge power to the remaining electrode.

7.2.5 LDO2

The TPS65471 has a 3.2-V regulator as the LDO2 power and it provides a stable and accurate voltage of 3.2 V (± 32 mV). LDO2 is controlled by logic input EN_VLDO and source of supply is PWR. This output is turned off when the EN_VLDO is L.

Table 2. Output Control Truth Tables

EN_VLDO	LDO2	LDO4	4.25-V BOOST/LD
H	3.2 V (On)	3 V (On)	4.25 V (On)
L	0 V (Off)	0 V (Off)	0 V (Off)

EN_VLDO3	LDO3
H	3.2 V (On)
L	0 V (Off)

7.2.6 LDO3

The TPS65471 has a 3.2-V regulator as the LDO3 power and it provides a stable and accurate voltage of 3.2 V (± 64 mV). LDO3 is controlled by logic input EN_VLDO3 and source of supply is PWR. This output is turned off when the EN_VLDO3 is L.

7.2.7 LDO4

The TPS65471 has a 3-V regulator as the LDO4 power and it provides a stable and accurate voltage of 3 V (± 0.1 V). LDO4 is controlled by logic input EN_VLDO. This output is turned off when the EN_VLDO is L.

7.2.8 4.25-V Boost/LDO

The TPS65471 has a 4.25-V regulator and synchronous boost converter as the LED power. It provides a stable and accurate voltage of 4.25 V (± 85 mV) connected to the VLED4P25. The boost converter is based on a fixed frequency pulse-width-modulation (PWM) controller. This output is controlled by logic input EN_VLDO. If USB-port (VBUS pin) or AC-DC adapter (VAC pin) powers are detected, the 4.25-V LDO operates (PWR supply source), and the 4.25V synchronous boost converter stops operation. If the voltage on both VBUS pin and VAC pin are less than the Power Good voltage, the power is provided to VBAT pin from the Li-ion battery, then the 4.25-V synchronous boost converter operates and the 4.25-V LDO stops operation. Complying with Table 1, in USB suspend mode (even if the voltage of VBUS pin is greater than $V_{(VBUSPG)}$) the source of supply is the battery.

7.2.9 R, G and B

The TPS65471 has three open-drain outputs for LED drivers. The R output is controlled by logic input CTL_R, the G output is controlled by CTL_G and the B output is controlled by CTL_B. For example, the open-drain output of R pulls low (On) when the CTL_R pin goes to H level. The open-drain output turns off when the CTL_R is L. These functions can operate when the EN_VLDO is H.

7.2.10 MTRIN

The TPS65471 has one open-drain output for the motor driver. The MTRIN output is controlled by logic input CTL_MTR. The open-drain output of MTRIN pulls low (On) when the CTL_MTR pin goes to H level. The open-drain output is turned off when the CTL_MTR is L.

7.2.11 Reset Generator

The TPS65471 monitors the status of VLDO1 (LDO1) and has reset generator circuitry to indicate a reset signal to the system.

The reset signal output is L level when the voltage of VLDO1 is less than $V_{(RST)}$, and H level when the voltage of VLDO1 is greater than $V_{(RST)} + 0.14$ V. The Reset pin goes to H level $t_{dly(RESET)}$ after internal signal goes to H. The Reset terminal has a 100-k Ω pull-up resistor to VLDO1. Also the outputs of VLDO2, VLDO3, VDDO4 and VLED4P25 turn Off when the voltage of VLDO1 is less than $V_{(RST)}$. If VLDO1 becomes greater than $V_{(RST)} + 0.14$ V, these outputs are turned On at the input level of each control signal.

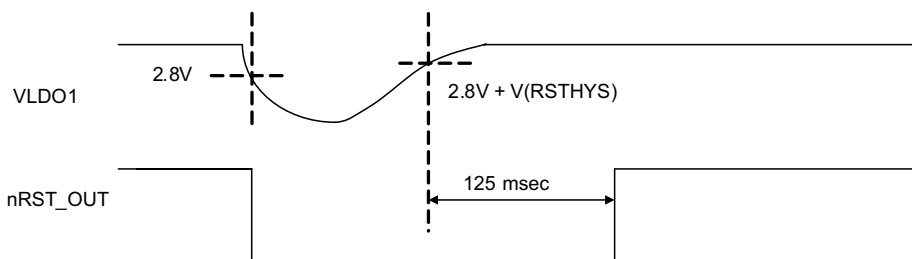


Figure 7. Timing of nRST_OUT Signal When a Voltage Drop Occurs on VLDO1

7.2.12 Charge Control

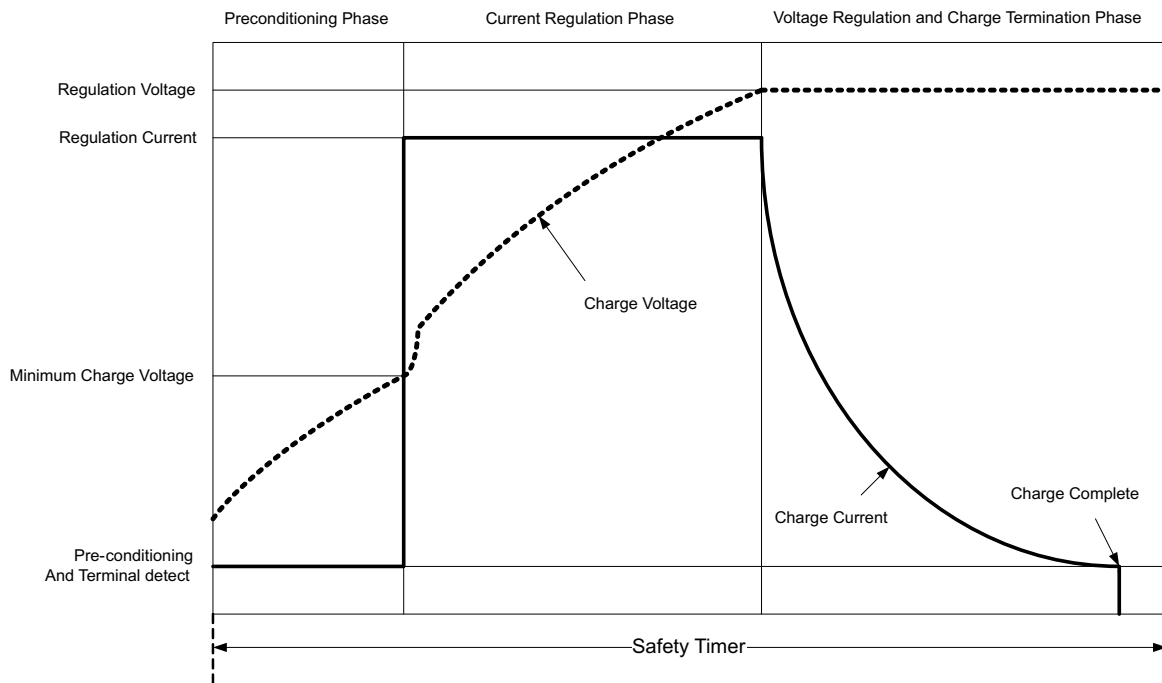


Figure 8. Charging Profile

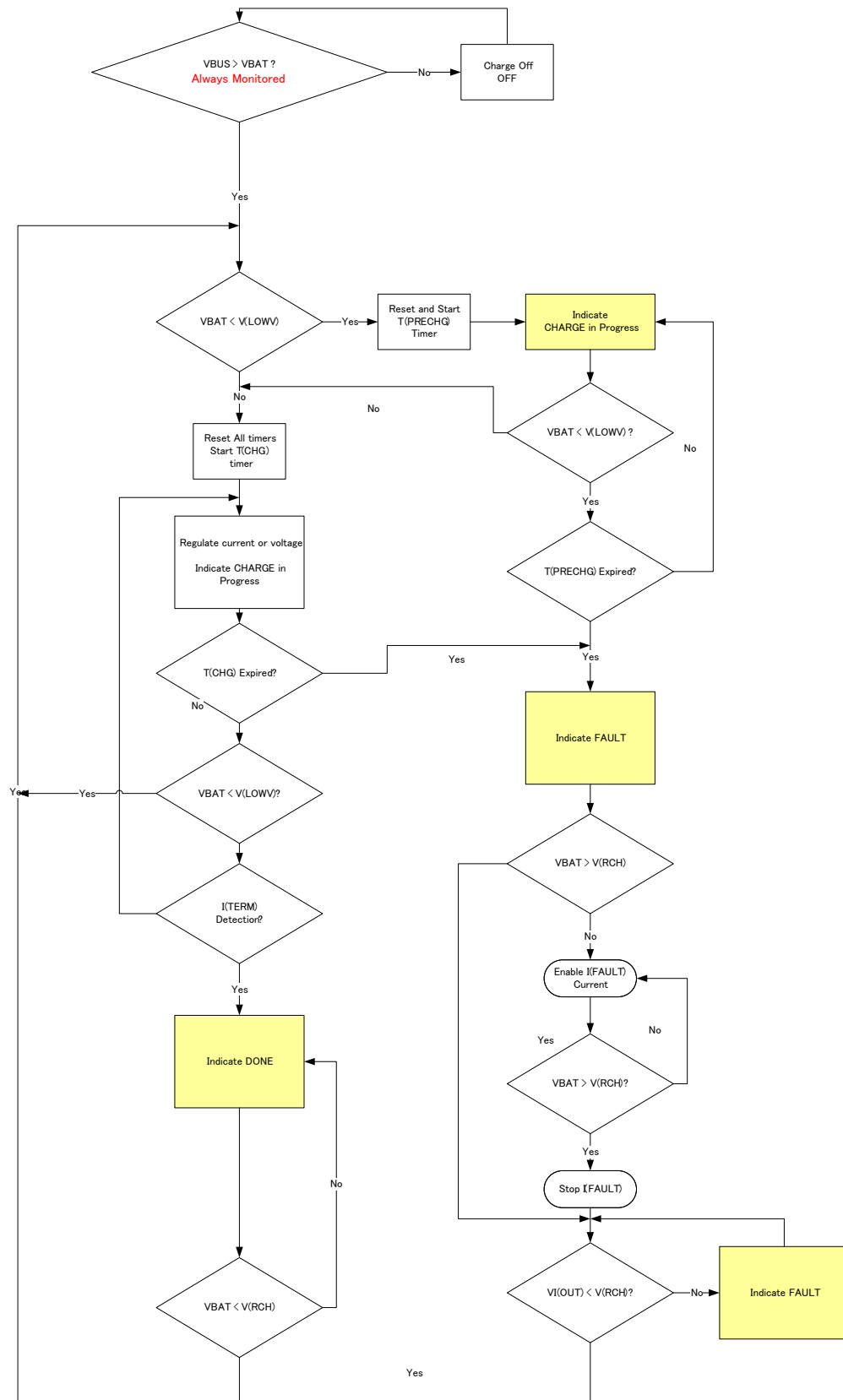


Figure 9. Charging Flow Chart

7.2.13 Battery Pre-Conditioning

During a charge cycle, if the battery voltage is below the $V_{(LOWV)}$ threshold, the device applies a pre-charge current, $I_{O(PRECHG)}$, to the battery. This feature revives deeply discharged cells. Resistor RSETn, connected between ISET1 and AGND and also between ISET1 and ISET2, determines the pre-charge rate. The $V_{(PRECHG)}$ and $K_{(SET)}$ parameters are specified in the Electrical Characteristics table.

$$I_{O(PRECHG)} = \frac{V_{(PRECHG)} \times K_{(SET)}}{R_{SET}} \quad (1)$$

TPS65471 activates a safety timer, $t_{(PRECHG)}$, during the conditioning phase. If the $V_{(LOWV)}$ threshold is not reached within the timer period, the device turns off the charger and enunciates FAULT on the STATx pins. See the Timer Fault Recovery section for additional details.

7.2.14 Battery Fast-Charge Constant Current

The TPS65471 offers on-chip current regulation with programmable set point. Resistor, RSETn, connected between the ISET1 and AGND and also connected between ISET1 and ISET2, determines the charge rate. The $V_{(SET)}$ and $K_{(SET)}$ parameters are specified in the Electrical Characteristics table.

$$I_{O(OUT)} = \frac{V_{(SET)} \times K_{(SET)}}{R_{SET}} \quad (2)$$

If USB-port (VBUS pin) is detected, MOS-FET of N channels connected to ISET2 turns off. The charge current is determined by the resistance of RSET1 connected between ISET1 and GND. If AC-DC adapter (VAC pin) is detected, MOS-FET of N channel connected to ISET2 turns on. The charge current is determined by the resistance of RSET1 and RSET2. When both VBUS and VAC are present, the charge current is determined by the resistance of RSET1 connected between ISET1 and AGND.

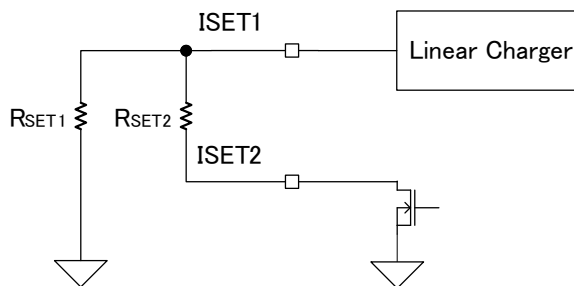


Figure 10. Equivalent Circuit ISET1 and ISET2 Terminals

7.2.15 Battery Fast-Charge Voltage Regulation

The voltage regulation feedback is through the VBAT pin. This input is tied directly to the positive side of the battery pack. The device monitors the battery-pack voltage between the VBAT and AGND pins. When the battery voltage rises to the $V_{O(REG)}$ threshold, the voltage regulation phase begins and the charging current begins to decrease.

As a safety backup, the device also monitors the charge time in charge mode. If charge is not terminated within this time period, $t_{(CHG)}$, the charger is turned off and FAULT is set on the STATx pins. See the Timer Fault and Recovery section for additional details.

7.2.16 Charge Termination Detection and Recharge

The TPS65471 monitors the charging current during the voltage regulation phase. Once the termination threshold, $I_{(TERM)}$, is detected, charge is terminated. The $V_{(TERM)}$ and $K_{(SET)}$ parameters are specified in the specifications.

$$I_{O(TERM)} = \frac{V_{(TERM)} \times K_{(SET)}}{R_{SET}} \quad (3)$$

After charge termination, the device restarts the charge once the voltage on the VBAT pin falls below the $V_{(RCH)}$ threshold. This feature keeps the battery at full capacity at all times.

The device monitors the charging current during the voltage regulation phase. Once the termination threshold, $I_{(TERM)}$, is detected, the charger is terminated immediately.

Resistors RSETn, connected between the ISET1 and AGND and also connected between ISET1 and ISET2, determine the current level at the termination threshold.

7.2.17 Charge Status Outputs

The open-drain STAT1 and STAT2 outputs indicate various charger operations as shown in [Table 3](#).

These status pins can be used to communicate to the host processor. Note that this open-drain output is powered by VLDO1 and an external pull-up resistor should be applied. Iso, note that OFF indicates the open-drain transistor is turns off.

Table 3. State of STAT1/STAT2 Pins

CHARGE STATE	STAT1	STAT2
Pre-charge in progress	ON	ON
Fast charge in progress	ON	OFF
Charge done	OFF	ON
Charge suspend, Timer Fault Any device state except #07#, #08#, #11#, #12# of charging	OFF	OFF

7.2.18 Charge Enable Signal

The nCHEN digital input can control a state of the charger function. If nCHEN is H level, TPS65471 stops all charge functions and turns the charger off.

7.2.19 Timer Fault Recovery

As shown in [Figure 9](#), the device provides a recovery method to deal with timer fault conditions. The following summarizes this method:

Condition Number 1: Charge voltage above recharge threshold ($V_{(RCH)}$) and timeout fault occurs.

Recovery Method: The device waits for the battery voltage to fall below the recharge threshold. This could happen as a result of a load on the battery, self-discharge, or battery removal. Once the battery voltage falls below the recharge threshold, the device clears the fault and starts a new charge cycle. A POR or nCHEN toggle also clears the fault.

Condition Number 2: Charge voltage below recharge threshold ($V_{(RCH)}$) and timeout fault occurs.

Recovery Method: Under this scenario, the device applies the $I_{(FAULT)}$ current. This small current is used to detect a battery removal condition and remains on as long as the battery voltage stays below the recharge threshold. If the battery voltage goes above the recharge threshold, then the device disables the $I_{(FAULT)}$ current and executes the recovery method described for Condition Number 1. Once the battery falls below the recharge threshold, the device clears the fault and starts a new charge cycle. A POR or nCHEN toggle also clears the fault.

7.2.20 Over Discharge Protection

TPS65471 monitors the voltage of Li-ion battery and protects it from over discharge.

If the voltage on VBAT pin is under $V_{(BATUVLO)}$, the current path from VBAT to the device is cut off and the current from the Li-ion battery will be minimized ($< I_{BAT(ODP)}$) as much as possible. This can prevent early battery degradation.

In this case, if the USB-port power source condition or AC-DC adaptor power source is good (state #03#, #04#, #09#, #10#), charge function can be enabled by nCHEN = L. Charge operation must be started from the pre-conditioning phase. When the pre-conditioning phase exceeds $V_{(BATUVLO)}$, the state of TPS65471 changes to (#07#, #08#, #11#, #12#).

7.2.21 Thermal Shut Down Function

When the junction temperature of TPS65471 increases higher than $T_{(SHTDWN)}$, the thermal shut down function is activated.

During a state of thermal shut down, all functions (for the charge, power paths LDO1, LDO2, LDO3, LDO4 and 4.25-V Boost/LDO) are turned off and any current is shut off. If the junction temperature decreases less than $T_{(SHTDWN)}$, (Note: -15°C (typical) hysteresis) TPS65471 goes back to normal operation. In this case, timers in the charger are not cleared. The charger timer maintains operation.

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Typical Application

Condition :

$V_{BUS} > V_{(VBUSPG)}$

or $V_{AC} > V_{(VACPG)}$

$nCHEN = L$

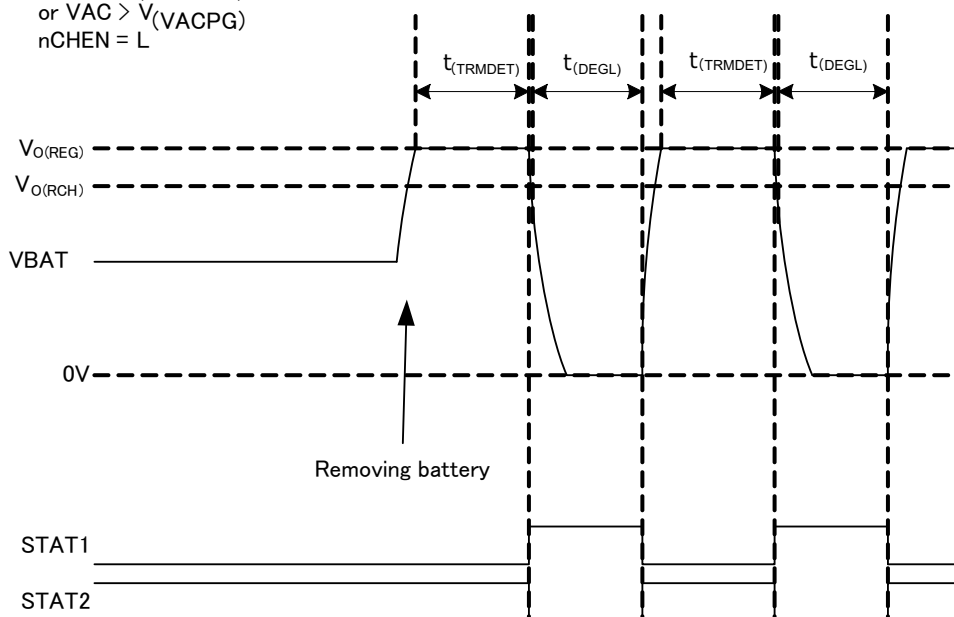


Figure 11. VBAT Waveform When Charging Without Battery Connection

8.1.1 Design Requirements

Table 4. Recommended Inductors and Capacitors

PIN	PARTS	VALUE	CHARACTERISTIC	NOTE
VBUS	Ceramic capacitor	1.0 μ F	X5R/X7R	
VAC	Ceramic capacitor	1.0 μ F	X5R/X7R	
VBAT	Ceramic capacitor	1.0 μ F	X5R/X7R	
PWR	Ceramic capacitor	10 μ F	X5R/X7R	Regarding an effect of DC bias on the capacitor, select a capacitor that can secure at least 4.7 μ F in worst case.
VLDO1	Ceramic capacitor	1.0 μ F	X5R/X7R	
VLDO2	Ceramic capacitor	1.0 μ F	X5R/X7R	
VLDO3	Ceramic capacitor	1.0 μ F	X5R/X7R	
VLDO4	Ceramic capacitor	1.0 μ F	X5R/X7R	
VLED4P25	Ceramic capacitor	22 μ F	X5R/X7R	
VIN	Ceramic capacitor	22 μ F	X5R/X7R	
Between SW and L	Inductor	6.8 μ H	$\pm 20\%$	NR4018T6R8M : TAIYO YUDEN or equivalent

8.1.2 Detailed Design Procedure

8.1.2.1 Behavior of the Charger Without Li-Ion Battery on VBAT Pin

If charger function is activated without the Li-ion battery on the VBAT pin, the charger shows the below phenomenon.

1. Voltage level of VBAT pin goes to 4.2 V.
2. After $t_{(TRMDET)}$ has passed, the charger function is turned off. Then the voltage level on the VBAT pin goes to GND.
3. Since the voltage level on the VBAT pin become less than $V_{O(RCH)}$, after $t_{(DEGL)}$ turns off, the charger function is activated again.
4. Return to 1.

8.1.2.2 Short Behaviors

8.1.2.2.1 VLDO1 Output Shorted to GND

If a short-circuit occurs between the 3.2-V LDO output (VLDO1) and GND, the current is limited by the LDO's current limit. If LDO is heated by the current and voltage, thermal shut down is activated (depending on ambient temperature and PCB structure).

8.1.2.2.2 VLDO2, VLDO4 or VLED4P25 Output Shorted to GND

If a short-circuit occurs between the output and GND, the current is limited by the LDO's current limit. If these output terminals decrease below LVP (low voltage protection), these power outputs will be turned off and this state will be held. In addition, if any output of VLDO2 or VLDO4 or VLED4P25 is connected to GND, all the outputs controlled by the signal of EN_VLDO are turned off. Recovery method, EN_VLDO pin goes to L level at once, then goes to H level.

8.1.2.2.3 VLDO3 Output Shorted to GND

If a short-circuit occurs between the 3.2-V LDO output (VLDO3) and GND, the current is limited by the LDO current limit. If this output terminal decreases below LVP, the power output will be turned off and this state will be held. Recovery method, EN_VLDO3 pin goes to L level at once, then goes to H level.

8.1.2.2.4 PWR Shorted to GND

(VBAT pin) Li-ion battery provides power to PWR. If a short-circuit is detected on the PWR pin, power-path SW2 goes to high-resistance mode immediately and limits this current. If the SW2 is heated by the current and voltage, thermal shut down is activated (depending on ambient temperature and PCB structure).

(VBUS pin or VAC pin) USB-port or AC-DC adaptor power provide power to PWR. If a short-circuit is detected on the PWR pin, current flows through power-path SW1 from VBUS to PWR. This current is limited by internal current limit on SW1. Short current flow through power-path SW3 from VAC to PWR is limited by internal current limit on SW3. If SW2 or SW3 is heated by the current and voltage, thermal shut down is activated (depending on ambient temperature and PCB structure).

8.1.2.2.5 VBAT Shorted to GND

If VBAT is shorted to GND, a protection IC in the battery pack will protect the battery.

9 Layout

9.1 Layout Guidelines

As for all switching power supplies, the layout is an important step in the design, especially at high peak currents and high switching frequencies. If the layout is not carefully done, the regulator could show stability problems as well as EMI problems.

1. Use wide and short traces for the main current path and for the power ground tracks without using vias if possible. If vias are unavoidable, use many vias in parallel to reduce resistance and inductance.
2. The input capacitor, output capacitor and the inductor should be placed as close as possible to the IC. These components should be placed on the same side of the printed circuit board. The order of placement for these components is output capacitor (VLED4P25 pin and PGND pin), inductor (L pin and SW pin), then input capacitor (VIN pin and ground plane).
3. Use of a ground plane is recommended.

Since TPS65471 provides charging current and system power with internal linear regulators, users need to consider thermal condition.

1. PowerPAD should be soldered to a thermal land on the PCB.
2. Vias on the thermal land of the PCB are necessary. This is a thermal path through the other side of the PCB.
3. A thermal pad of the same size is required on the other side of the PCB. All thermal pads should be connected by vias.
4. A metal layer should cover all of the PCB if possible.
5. Place vias to connect other sides to create thermal paths.

With these steps, the thermal resistance of TPS65471 can be lowered.

10 Device and Documentation Support

10.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

10.2 Trademarks

PowerPAD, E2E are trademarks of Texas Instruments.
All other trademarks are the property of their respective owners.

10.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

10.4 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS65471RHAR	ACTIVE	VQFN	RHA	40	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	0 to 0	TPS 65471	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS65471RHAR	VQFN	RHA	40	2500	330.0	16.4	6.3	6.3	1.1	12.0	16.0	Q2

TAPE AND REEL BOX DIMENSIONS

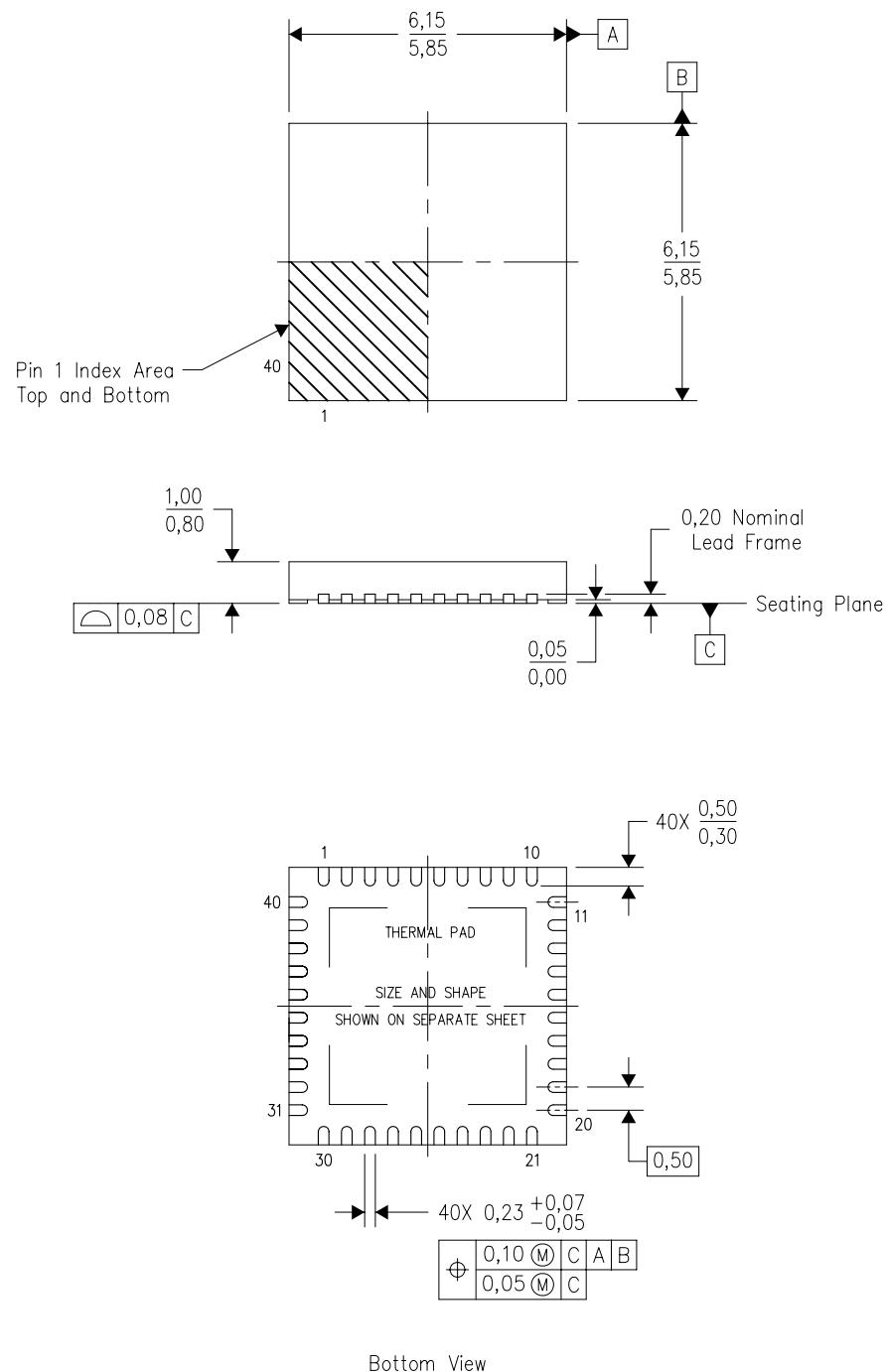


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS65471RHAR	VQFN	RHA	40	2500	367.0	367.0	38.0

RHA (S-PVQFN-N40)

PLASTIC QUAD FLATPACK NO-LEAD



4204276/E 06/11

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. QFN (Quad Flatpack No-Lead) Package configuration.
 - D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
 - E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 - F. Package complies to JEDEC MO-220 variation VJJD-2.

THERMAL PAD MECHANICAL DATA

RHA (S-PVQFN-N40)

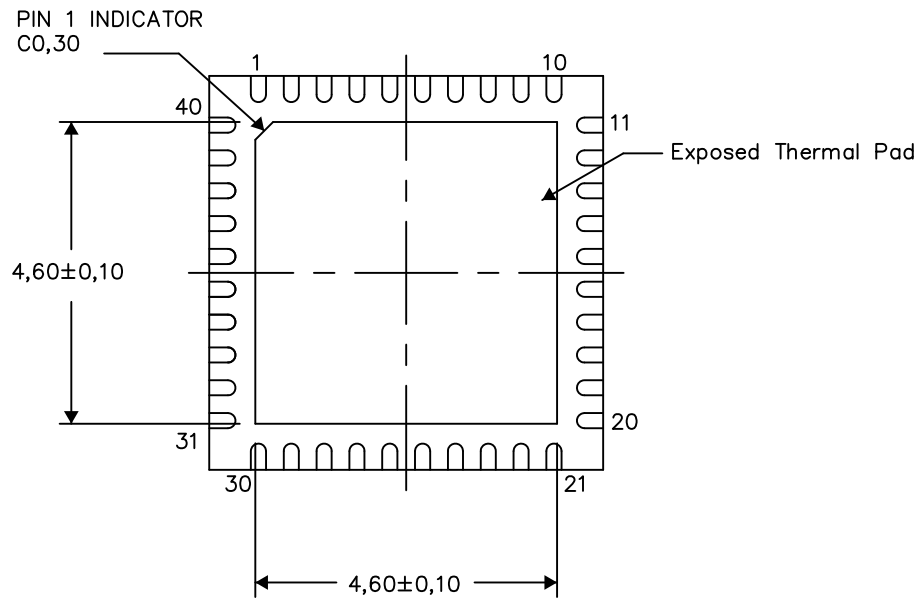
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

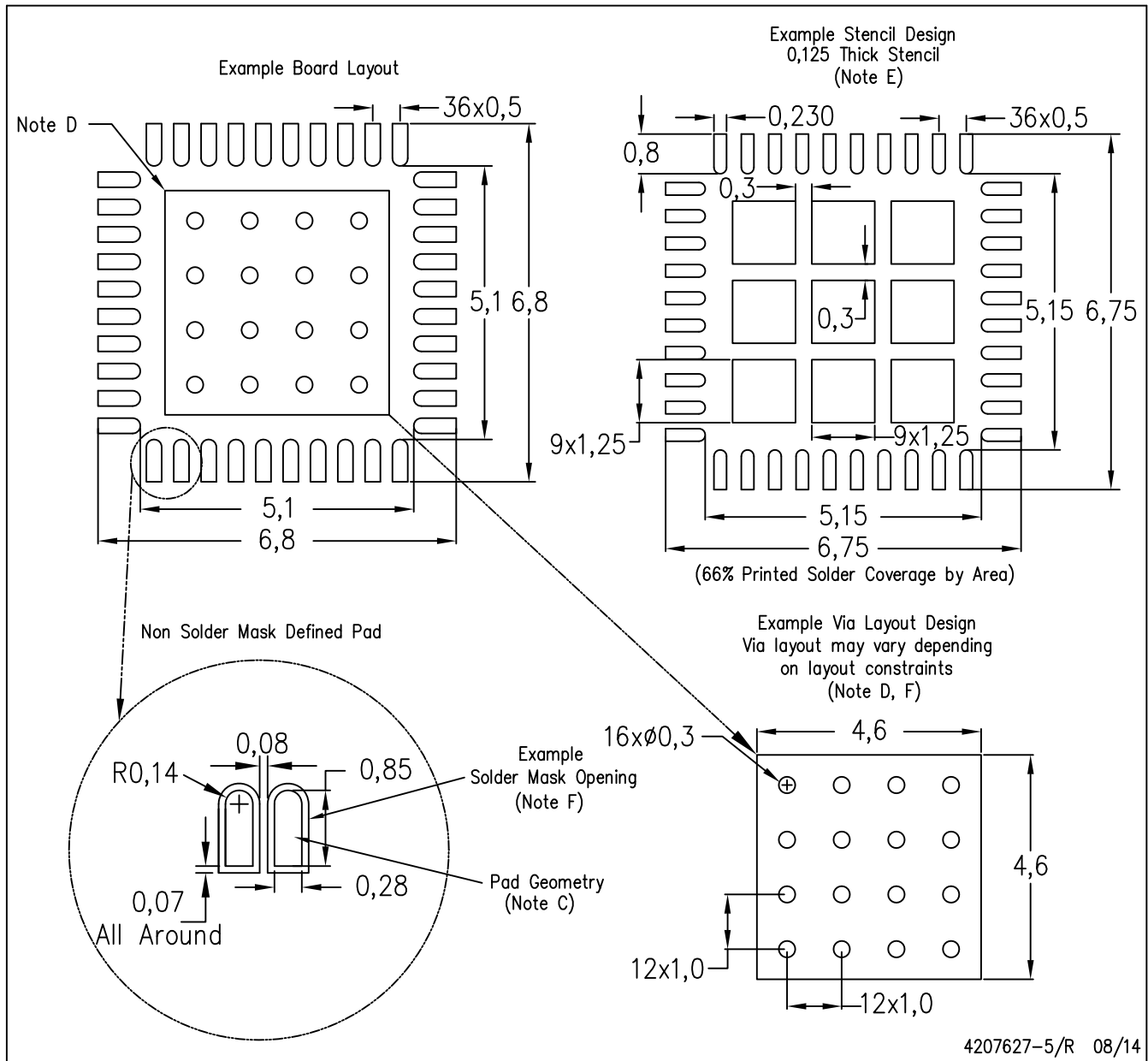
Exposed Thermal Pad Dimensions

4206355-5/X 08/14

NOTES: A. All linear dimensions are in millimeters

RHA (S-PVQFN-N40)

PLASTIC QUAD FLATPACK NO-LEAD



4207627-5/R 08/14

- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <<http://www.ti.com>>.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
 - Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.

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